# **BLF7G20L-90P**; BLF7G20LS-90P Power LDMOS transistor

**AMPLEON** 

Rev. 3 — 1 September 2015

Product data sheet

#### **Product profile**

#### 1.1 General description

90 W LDMOS power transistor for base station applications at frequencies from 1800 MHz to 2000 MHz, designed for operation at 1427 MHz to 1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz.

**Typical performance** 

Typical RF performance at  $T_{case} = 25$  °C in a common source class-AB production test circuit.

Mode of operation	f	$I_{Dq}$	V <sub>DS</sub>	$P_{L(AV)}$	Gp	$\eta_{D}$	ACPR <sub>400k</sub>	ACPR <sub>600k</sub>	<b>EVM</b> <sub>rms</sub>
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)	(%)
CW	1805 to 1880	550	28	84	19	54	-	-	-
GSM EDGE	1805 to 1880	550	28	40	19.5	41	<b>–61</b>	<b>-74</b>	2.5

#### 1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R<sub>th</sub> providing excellent thermal stability
- Designed for broadband operation (1427 MHz to1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

#### 1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the frequency bands of 1427 MHz to 1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz.

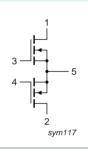
### 2. Pinning information

Table 2. Pinning

	9			
Pin	Description		Simplified outline	Graphic symbol
BLF7G20I	L-90P (SOT1121A)			
1	drain1			
2	drain2		1 2 [~] [~]	
3	gate1		5	3
4	gate2			5
5	source	<u>[1]</u>	3 4	4
				' <u> </u>
				2 sym117

BLF7G20LS-90P	(SOT1121B)
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1	drain1	
2	drain2	
3	gate1	
4	gate2	
5	source	[1]



## 3. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
BLF7G20L-90P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A				
BLF7G20LS-90P	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121B				

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	65	V
$V_{GS}$	gate-source voltage		-0.5	+13	V
$I_D$	drain current		-	18	Α
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		-	200	°C

<sup>[1]</sup> Connected to flange.

#### 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case} = 80  ^{\circ}C;  P_{L} = 90  W$	0.49	K/W

#### 6. Characteristics

#### Table 6. Characteristics

 $T_i = 25$  °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_{D} = 0.5 \text{ mA}$	65	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS}$ = 10 V; $I_{D}$ = 50 mA	1.5	1.9	2.3	V
I <sub>DSS</sub>	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	8.2	9.5	-	Α
$I_{GSS}$	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	200	nA
g <sub>fs</sub>	forward transconductance	$V_{DS}$ = 10 V; $I_{D}$ = 2.5 A	-	3.8	-	S
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 1.75 A$	-	0.28	-	Ω

#### 7. Test information

#### Table 7. Application information

f = 1805 MHz to 1880 MHz; RF performance at  $V_{DS}$  = 28 V;  $I_{Dq}$  = 550 mA;  $T_{case}$  = 25 °C; 2 sections combined unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Mode of o	peration: GSM EDGE; P <sub>L(AV)</sub> = 40 W					
Gp	power gain		18.3	19.5	-	dB
RLin	input return loss		-	-15	-8	dB
$\eta_{D}$	drain efficiency		38	41	-	%
ACPR <sub>400k</sub>	adjacent channel power ratio (400 kHz)		-	-61	-58	dBc
ACPR <sub>600k</sub>	adjacent channel power ratio (600 kHz)		-	-74	-70.5	dBc
$EVM_{rms}$	RMS EDGE signal distortion error		-	2.5	3.8	%
$EVM_M$	peak EDGE signal distortion error		-	8	12.5	%
Mode of o	peration: CW; P <sub>L(AV)</sub> = 84 W					
Gp	power gain		17.8	19	-	dB
$\eta_{D}$	drain efficiency		51	54	-	%

#### 7.1 Ruggedness in class-AB operation

The BLF7G20L-90P and BLF7G20LS-90P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:

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V_{DS} = 28 \text{ V; } I_{Dq} = 550 \text{ mA; } P_L = 90 \text{ W (CW), } f = 1805 \text{ MHz,} \\ V_{DS} = 28 \text{ V; } I_{Dq} = 380 \text{ mA; } P_L = 40 \text{ W (CW, half device), } f = 2110 \text{ MHz,} \\ V_{DS} = 28 \text{ V; } I_{Dq} = 380 \text{ mA; } P_L = 55 \text{ W (CW pulse, } 10 \text{ %, } 100 \text{ } \mu\text{s, halve device),} \\ f = 1427 \text{ MHz.}
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#### 7.2 One-tone CW

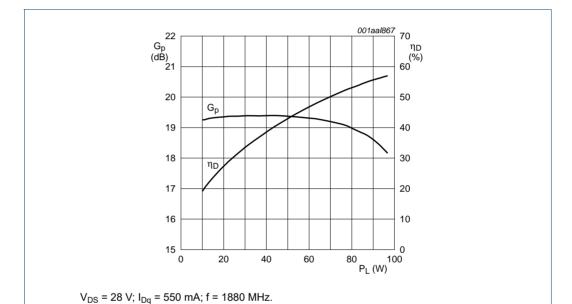


Fig 1. One-tone CW power gain and drain efficiency as function of load power; typical values

#### 7.3 Two-tone CW

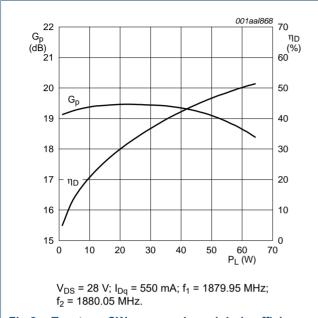
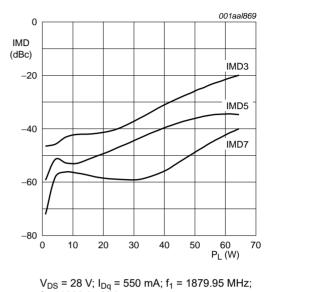


Fig 2. Two-tone CW power gain and drain efficiency as function of load power; typical values



 $f_2$  = 1880.05 MHz. Fig 3. Two-tone CW intermodulation distortion as a

function of load power; typical values

#### 7.4 GSM EDGE

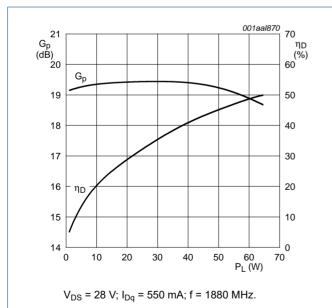


Fig 4. GSM EDGE power gain and drain efficiency as function of load power; typical values

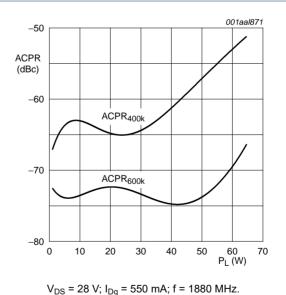
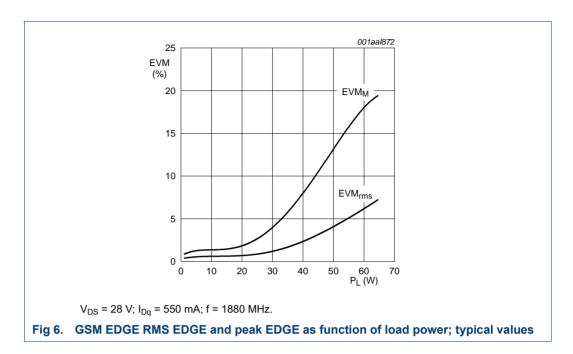


Fig 5. GSM EDGE ACPR at 400 kHz and at 600 kHz as function of load power; typical values



#### 7.5 Single carrier IS-95

Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

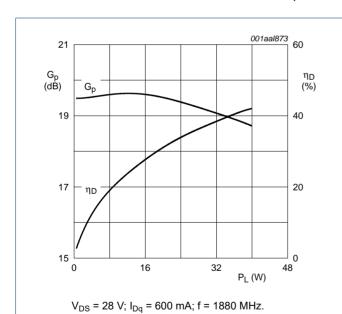
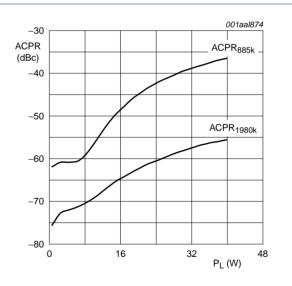
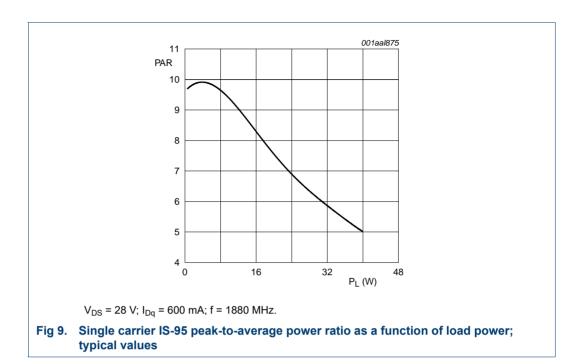


Fig 7. Single carrier IS-95 power gain and drain efficiency as function of load power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 600 mA; f = 1880 MHz.

Fig 8. Single carrier IS-95 ACPR at 885 kHz and at 1980 kHz as function of load power; typical values



#### 7.6 Single carrier W-CDMA

3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

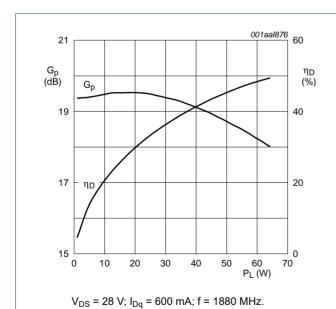
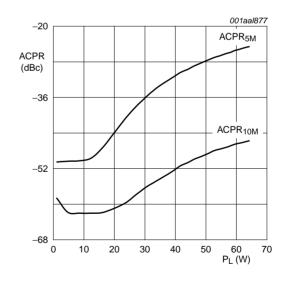


Fig 10. Single carrier W-CDMA power gain and drain efficiency as function of load power; typical values



 $V_{DS}$  = 28 V;  $I_{Dq}$  = 600 mA; f = 1880 MHz.

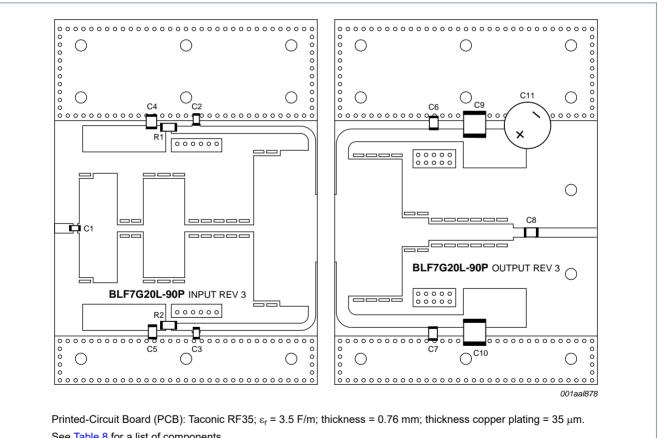
Fig 11. Single carrier W-CDMA ACPR at 5 MHz and at 10 MHz as function of load power; typical values

#### 7.7 Test circuit

Table 8. List of components For test circuit see Figure 12.

Component	Description	Value	Remarks
C1, C2, C3	multilayer ceramic chip capacitor	24 pF	[1]
C4, C5	multilayer ceramic chip capacitor	4.7 μF	[2]
C6, C7, C8	multilayer ceramic chip capacitor	11 pF	[3]
C9, C10	multilayer ceramic chip capacitor	10 μF	[2]
C11	electrolytic capacitor	470 μF; 63 V	
R1, R2	SMD resistor	12 Ω	Philips 1206

- American Technical Ceramics type 100A or capacitor of same quality.
- TDK or capacitor of same quality.
- American Technical Ceramics type 100B or capacitor of same quality.



See Table 8 for a list of components.

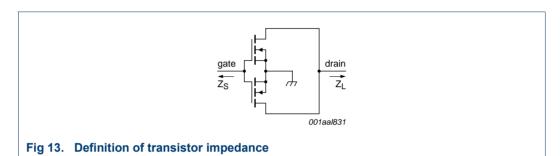
Fig 12. Component layout for class-AB production test circuit

#### 7.8 Impedance information

Table 9. Typical impedance

Typical values valid for both section in parallel unless otherwise specified.

f	Z <sub>S</sub>	Z <sub>L</sub>
MHz	Ω	Ω
1800	1.0 – j3.3	2.8 – j2.7
1840	1.2 – j3.3	2.8 – j2.5
1880	1.1 – j3.4	2.7 – j2.4



#### 8. Package outline

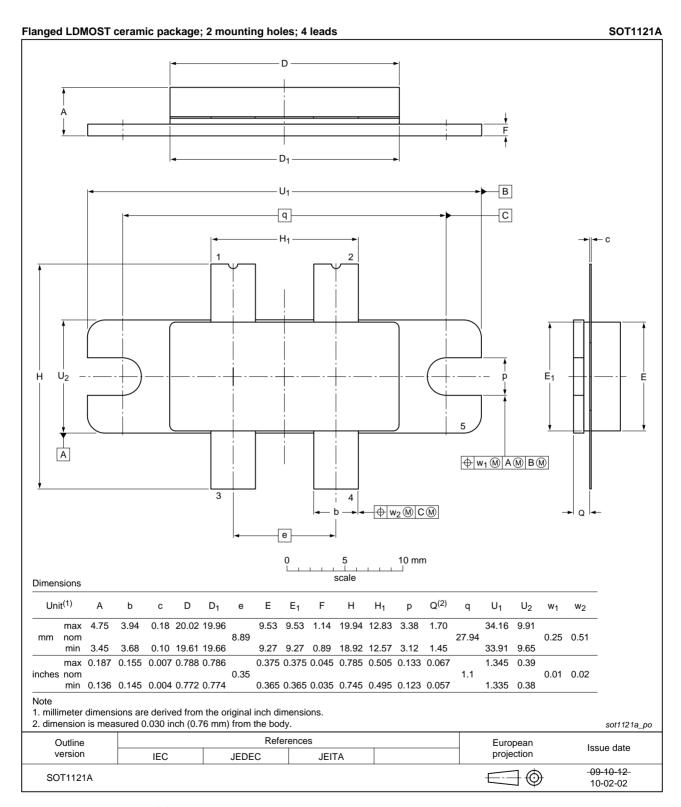


Fig 14. Package outline SOT1121A

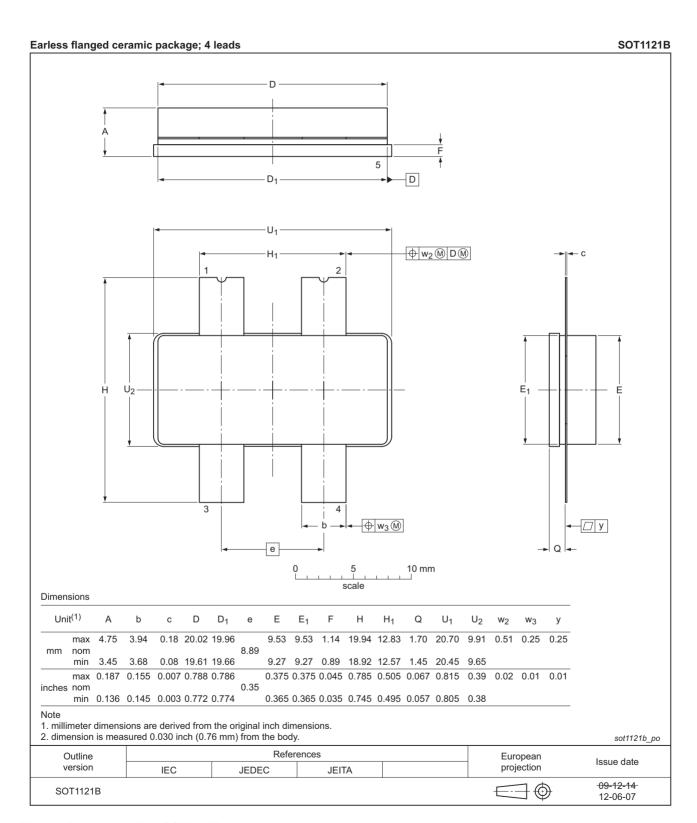


Fig 15. Package outline SOT1121B

#### 9. Abbreviations

Table 10. Abbreviations

/ 10010	
Acronym	Description
3GPP	3rd Generation Partnership Project
CW	Continuous Wave
CCDF	Complementary Cumulative Distribution Function
DPCH	Dedicated Physical Channel
EDGE	Enhanced Data rates for GSM Evolution
ESD	ElectroStatic Discharge
GSM	Global System for Mobile Communications
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access
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## 10. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLF7G20L-90P_7G20LS-90P#3	20150901	Product data sheet	-	BLF7G20L-90P_7G20LS- 90P v.2
Modifications:	<ul> <li>The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
BLF7G20L-90P_7G20LS-90P v.2	20111020	Product data sheet	-	BLF7G20L-90P_7G20LS- 90P v.1
BLF7G20L-90P_7G20LS-90P v.1	20100428	Product data sheet	-	-

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#### 11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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BLF7G20L-90P 7G20LS-90P#3

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**Power LDMOS transistor** 

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## BLF7G20L-90P; BLF7G20LS-90P

## **AMPLEON**

**Power LDMOS transistor** 

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